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PHOTOMULTIPLIER TUBE R1464

High Anode Sensitivity at Low Supply Voltage 19mm (3/4 Inch) Diameter, 10 Stage, Head-On Type 185 to 850nm Response Multialkali Photocathode

The Hamamatsu R1464 is a 19mm (3/4") diameter, head-on type photomultiplier tube having a multialkali photocathode designed for use in UV to near IR spectrophotometers and other analysis equipments where wide range response and high gain are of importance. The R1464 exhibits a high anode sensitivity at relatively low supply voltage by virtue of improvement in secondary emitting surface, compared with the Hamamatsu R663 photomultiplier tube which has the same spectral response characteristic and mechanical specifications as the R1464.

FEATURES

- Wide Spectral Response 185 to 850nm
- Low Anode Dark Current 10 nA at 1000V

APPLICATIONS

- UV to Near IR Spectrophotometers
- Laser Detection Systems
- Photon Counting Systems

GENERAL

I	Parameter	Description/Value	Unit
Spectral Response		185 to 850	nm
Wavelength of Maximum Response		420	nm
Photocothodo	Material	Multialkali	_
Photocathode	Minimum Useful Size	15	mm dia.
Window	Material	UV glass	—
	Shape	Plano-plano	_
Dynode	Secondary Emitting Surface	Multialkali	_
	Structure	Linear focused	
	Number of Stages	10	
Direct Interelectrode	Anode to Last Dynode	1.7	pF
Capacitances (Approx.)	Anode to All Other Electrodes	3.5	pF
Base	·	12 pin glass base	
Weight		14	g
Suitable Socket		E678-12D (supplied)	—
Suitable Socket Assembly		E974-05 (option)	_

MAXIMUM RATINGS (Absolute Maximum Values)

Pa	arameter	Value	Unit	
Supply Voltage	Between Anode and Cathode	1250	Vdc	
	Between Anode and Last Dynode	250	Vdc	
Average Anode Current (No	te 1)	0.1	mA	
Average Cathode Current (Note 1)		100	nA/cm ²	
Ambient Temperature		-80 to +50	О°	

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CHARACTERISTICS (at 25°C)

Pa	rameter	Min.	Тур.	Max.	Unit
Apada Sanaitivity (Nata 2)	Luminous (Note 3)	30	120	—	A/Im
	Radiant at 350nm	—	$4.9 imes10^4$	—	A/W
Anode Sensitivity (Note 2)	at 420nm	—	5.1 × 104		A/W
	at 633nm	—	1.9×10^{4}	—	A/W
Cathode Sensitivity	Luminous (Note 4)	80	120	—	μA/Im
	Radiant at 350nm	—	49	—	mA/W
	at 420nm	—	51	—	mA/W
	at 633nm	—	19	—	mA/W
	Quantum Efficiency at 290nm	—	19	—	%
	Red/White Ratio (Note 5)	0.15	0.2	—	
Gain (Note 2)		—	1 × 10 ⁶	—	_
Anode Dark Current (Note 2)	After 30 minute storage in the dark	—	4	20	nA
ENI (Equivalent Noise Input) (Note 6)		—	7 × 10 ⁻¹⁶	—	W
Time Response	Anode Pulse Rise Time (Note 2, 7)	—	2.5	—	ns
	Electron Transit Time (Note 2, 8)		27		ns

NOTES

- 1: Averaged over any interval of 30 seconds maximum.
- 2: The Voltage distribution ratio is shown in Table 1 below.
- 3: The light source is a tungsten filament lamp operated at a distribution temperature of 2856K. The light input is 0.1 micro-lumen.
- 4: Under the same conditions as Note 3 except that the light input is 10⁻² lumen and 150 volts are applied between cathode and all other electrode connected together as anode.
- 5: Red/White Ratio is quotient of the cathode current measured using a red filter (Toshiba R-68) interposed between the light source and the tube by the cathode current measured with the filter removed under the same conditions as Note 4.
- 6: ENI is an indication of photon limited signal-to-noise ratio. It refers to the amount of light in watts to produce a signal-to-noise ratio in unity in the output of a photomultiplier tube. In this catalog the value of peak wavelength is described. ENI is given by the following formula:

 $\mathsf{ENI} = \frac{\sqrt{2q} \cdot \mathsf{Idb} \cdot \mathsf{G} \cdot \Delta \mathsf{f}}{\mathsf{S}}$

- where q = Elementary charge (1.60×10^{-19} coulomb)
 - Idb = PMT anode dark current (after 30 minute storage) in amperes
 - G = PMT gain
 - Δf = Bandwidth of the system in hertz. In this catalog, 1 Hz bandwidth is used.
 - S = Anode radiant sensitivity in amperes per watt at the wavelength of peak response.
- 7: The rise time is the time for the output pulse to rise from 10% to 90% of the peak amplitude when the entire photocathode is illuminated by a delta function light pulse.
- 8: The electron transit time is the interval between the arrival of a delta function light pulse at the entrance window of the tube and the time the output pulse reaches the peak amplitude. In measurement the entire photocathode is illuminated.

Table 1: VOLTAGE DISTRIBUTION RATIO

Electrodes	K	(D	y1	Dy	2	Dy3	Dy	/4	Dy	5 1	Dy6	Dy	y7	Dy8	8 C	9y9	Dy	10	F	>
Distribution Ra	tio	1.5	1		1	-	1	1		1		1	1		1	-	1	1		

Supply Voltage: 1000Vdc, K: Cathode, Dy: Dynode, P: Anode



Figure 1: Typical Spectral Response

WAVELENGTH (nm)

Figure 2: Anode Sensitivity and Gain Characteristics



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Figure 4: Typical Temperature Coefficient of Anode Sensitivity



Figure 5: Typical Temperature Characteristic of Dark Current (After 30 minute storage)



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Figure 6: Dimensional Outline (Unit: mm)





Figure 7: Optional Socket Assembly E974-13 (Unit: mm)

The E974-13 is socket assembly specifically designed for 3/4 inch diameter, 10 stage, head-on type photomultiplier tubes having a 12-pin glass base. It contains a voltage-divider network potted with silicone rubber, thus eliminating troublesome soldering for making up the divider network.



Warning - Personal Safety Hazards Electrical Shock — Operating voltage applied to this device presents shock hazard.

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